NSN 5961-01-147-2502



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-147-2502 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** 0.380 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 650.0 collector to base voltage/static/emitter open and 400.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 6.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead **Specification Data:**

Demilitarization:

Unit Of Measure:

Shelf Life:

N/a

81349-mil-s-19500/538 government specification

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